Yanghua Lu, é**₹**™³åŽ

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/7243752/publications.pdf

Version: 2024-02-01

430874 477307 1,125 29 18 29 g-index citations h-index papers 29 29 29 1345 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	Monolayer MoS 2 /GaAs heterostructure self-driven photodetector with extremely high detectivity. Nano Energy, 2016, 23, 89-96.	16.0	138
2	A High Current Density Direct urrent Generator Based on a Moving van der Waals Schottky Diode. Advanced Materials, 2019, 31, e1804398.	21.0	109
3	High performance graphene/semiconductor van der Waals heterostructure optoelectronic devices. Nano Energy, 2017, 40, 122-148.	16.0	96
4	Enhanced performance of a graphene/GaAs self-driven near-infrared photodetector with upconversion nanoparticles. Nanoscale, 2018, 10, 8023-8030.	5 . 6	84
5	Broadband surface plasmon resonance enhanced self-powered graphene/GaAs photodetector with ultrahigh detectivity. Nano Energy, 2018, 47, 140-149.	16.0	82
6	Co-harvesting Light and Mechanical Energy Based on Dynamic Metal/Perovskite Schottky Junction. Matter, 2019, 1, 639-649.	10.0	77
7	The Interaction between Quantum Dots and Graphene: The Applications in Grapheneâ€Based Solar Cells and Photodetectors. Advanced Functional Materials, 2018, 28, 1804712.	14.9	69
8	Direct-Current Generator Based on Dynamic PN Junctions with the Designed Voltage Output. IScience, 2019, 22, 58-69.	4.1	68
9	Surface States Enhanced Dynamic Schottky Diode Generator with Extremely High Power Density Over 1000 W m ^{â^2} . Advanced Science, 2019, 6, 1901925.	11.2	50
10	ZnO quantum dot-doped graphene/h-BN/GaN-heterostructure ultraviolet photodetector with extremely high responsivity. Nanotechnology, 2016, 27, 48LT03.	2.6	43
11	Tunable Dynamic Black Phosphorus/Insulator/Si Heterojunction Direct-Current Generator Based on the Hot Electron Transport. Research, 2019, 2019, 5832382.	5 . 7	35
12	Quasi-industrially produced large-area microscale graphene flakes assembled film with extremely high thermoelectric power factor. Nano Energy, 2019, 58, 63-68.	16.0	30
13	Surface plasmon enhanced graphene/p-GaN heterostructure light-emitting-diode by Ag nano-particles. Nano Energy, 2016, 30, 362-367.	16.0	28
14	Enhanced monolayer MoS2/InP heterostructure solar cells by graphene quantum dots. Applied Physics Letters, 2016, 108, 163901.	3.3	26
15	Polarized Water Driven Dynamic PN Junction-Based Direct-Current Generator. Research, 2021, 2021, 7505638.	5.7	26
16	Interfacial Built-In Electric Field-Driven Direct Current Generator Based on Dynamic Silicon Homojunction. Research, 2020, 2020, 5714754.	5.7	24
17	Graphene/p-AlGaN/p-GaN electron tunnelling light emitting diodes with high external quantum efficiency. Nano Energy, 2019, 60, 836-840.	16.0	20
18	Direct Current Electricity Generation from Dynamic Polarized Water–Semiconductor Interface. Journal of Physical Chemistry C, 2021, 125, 14180-14187.	3.1	20

#	Article	IF	CITATIONS
19	Dynamic Schottky Diode Directâ€Current Generator under Extremely Low Temperature. Advanced Functional Materials, 2021, 31, 2105325.	14.9	19
20	Dynamics and physical process of hot carriers in optoelectronic devices. Nano Energy, 2022, 95, 106977.	16.0	16
21	Wind driven semiconductor electricity generator with high direct current output based on a dynamic Schottky junction. RSC Advances, 2021, 11, 19106-19112.	3.6	12
22	Multi-type quantum dots photo-induced doping enhanced graphene/semiconductor solar cell. RSC Advances, 2017, 7, 33413-33418.	3.6	11
23	Graphene/Semiconductor Heterostructure Wireless Energy Harvester through Hot Electron Excitation. Research, 2020, 2020, 3850389.	5.7	11
24	Gate tunable surface plasmon resonance enhanced graphene/Ag nanoparticles-polymethyl methacrylate/graphene/p-GaN heterostructure light-emitting diodes. Optics Express, 2018, 26, 25257.	3.4	9
25	Hot carriers assisted mixed-dimensional graphene/MoS2/p-GaN light emitting diode. Carbon, 2022, 197, 192-199.	10.3	9
26	Hot Carrier Transport and Carrier Multiplication Induced High Performance Vertical Graphene/Silicon Dynamic Diode Generator. Advanced Science, 2022, 9, .	11.2	8
27	Van der Waals contacted MoOx staked ZnO/GaN vertical heterostructured ultraviolet light emitting diodes. Optics Express, 2020, 28, 31603.	3.4	3
28	Highâ€Performance Graphene/GalnP Solar Cell Prepared by Interfacial Chemical Modification with Poly(3,4â€Ethylenedioxythiophene):Poly(styrenesulfonate). Energy Technology, 2021, 9, 2100122.	3.8	1
29	Van der Waals Integrated Silicon/Graphene/AlGaN Based Vertical Heterostructured Hot Electron Light Emitting Diodes. Nanomaterials, 2020, 10, 2568.	4.1	1